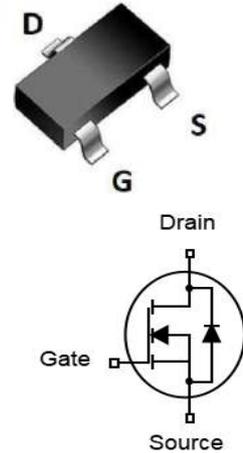


Features

- N-Channel
- Fast switching
- Very Low On-resistance $R_{DS(ON)}$
- Low C_{rss}
- Improved dv/dt capability

V_{DS}	20	V
$R_{DS(on),TYP@ V_{GS}=4.5V}$	21.5	m Ω
$R_{DS(on),TYP@ V_{GS}=2.5V}$	28.5	m Ω
I_D	4	A

SOT-23


Part ID	Package Type	Marking	Packing
ZT2302A	SOT-23	2302	3000pcs/Reel

Absolute Maximum Ratings $T_A = 25^\circ\text{C}$, unless otherwise specified

Symbol	Parameter	Rating	Unit	
Common Ratings ($T_c=25^\circ\text{C}$ Unless Otherwise Noted)				
V_{GS}	Gate-Source Voltage	± 10	V	
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	20	V	
T_J	Maximum Junction Temperature	150	$^\circ\text{C}$	
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$	
T_L	Maximum Temperature for Soldering	300	$^\circ\text{C}$	
I_{DM}	Drain Current-Continuous@ Current-Pulsed (Note 1)	$T_c = 25^\circ\text{C}$ 12	A	
Mounted on Large Heat Sink				
I_D	Drain Current-Continuous	$T_c = 25^\circ\text{C}$	4.0	A
		$T_c = 70^\circ\text{C}$	3.0	A
P_D	Maximum Power Dissipation	1.2	W	
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	101	$^\circ\text{C/W}$	

Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T_J=25°C (unless otherwise stated)						
V(BR)DSS	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	20	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =20V, V _{GS} =0V	--	--	1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±10V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	0.45	--	1.1	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =4.5V, I _D =4A	--	21.5	30	mΩ
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =2.5V, I _D =3A	--	28.5	40	mΩ
Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
C _{iss}	Input Capacitance	V _{DS} =10V, V _{GS} =0V, f=1MHz	--	306	--	pF
C _{oss}	Output Capacitance		--	60	--	pF
C _{rss}	Reverse Transfer Capacitance		--	56	--	pF
Q _g	Total Gate Charge	V _{DS} =10V, I _D =4A, V _{GS} =5V	--	4.1	--	nC
Q _{gs}	Gate-Source Charge		--	0.6	--	nC
Q _{gd}	Gate-Drain Charge		--	1.8	--	nC
Switching Characteristics						
T _{d(on)}	Turn-on Delay Time	V _{DS} =10V, I _D =4A, R _G =6Ω, V _{GS} =5V	--	5	--	ns
T _r	Turn-on Rise Time		--	35	--	ns
T _{d(off)}	Turn-Off Delay Time		--	14.5	--	ns
T _f	Turn-Off Fall Time		--	5.6	--	ns
Source- Drain Diode Characteristics @ T_J = 25°C (unless otherwise stated)						
I _{SD}	Source-Drain Current (Body Diode)		--	--	4	A
V _{SD}	Forward on voltage	I _S =4A, V _{GS} =0V	--	--	1.2	V

Notes:

1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature
2. Device mounted on FR-4 PCB, 1inch x 0.85inch x 0.062 inch
3. Pulse Test: Pulse Width≤300μs, Duty Cycles≤0.5%

N- Channel Typical Characteristics

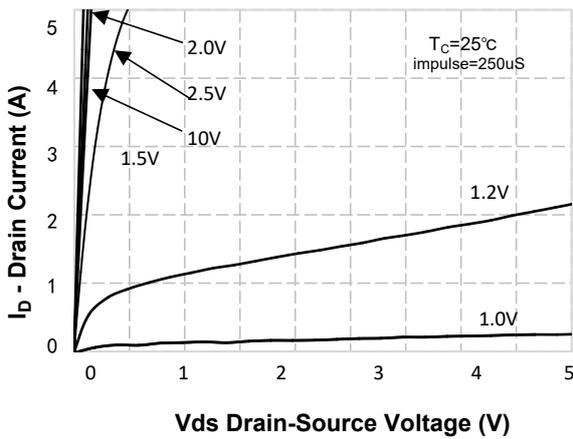


Figure 1. On-Region Characteristics

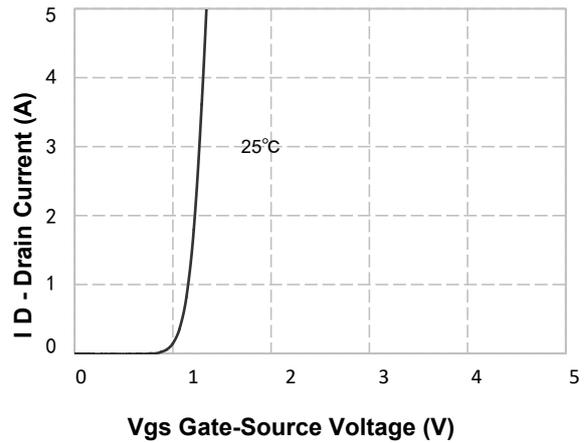


Figure 2. Transfer Characteristics

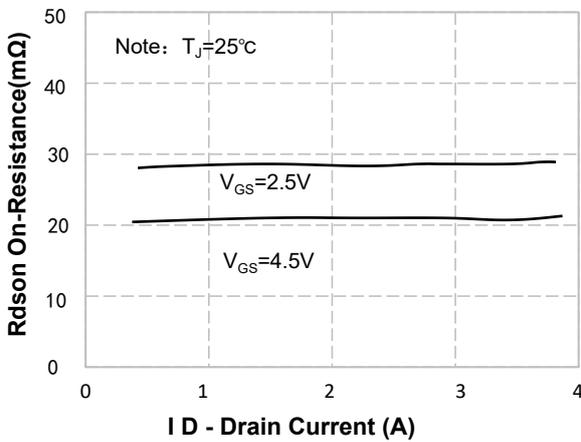


Figure 3. On-Resistance Variation vs Drain Current and Gate Voltage

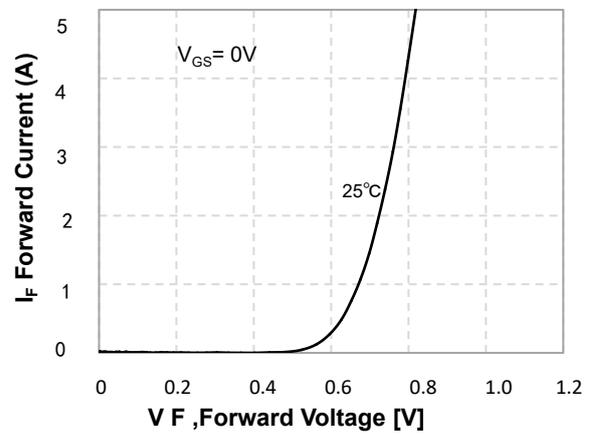


Figure 4. Body Diode Forward Voltage Variation with Source Current

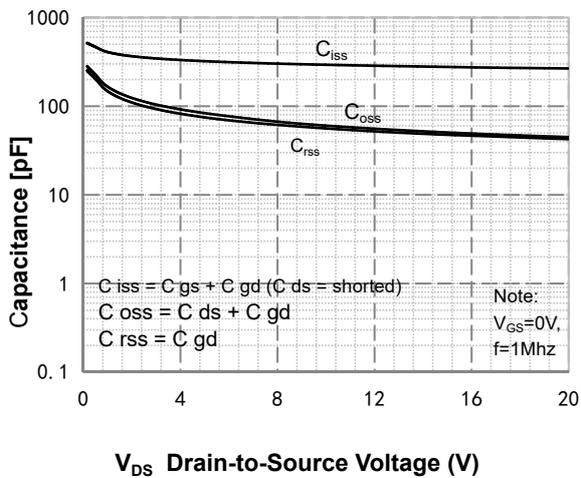


Figure 5. Capacitance Characteristics

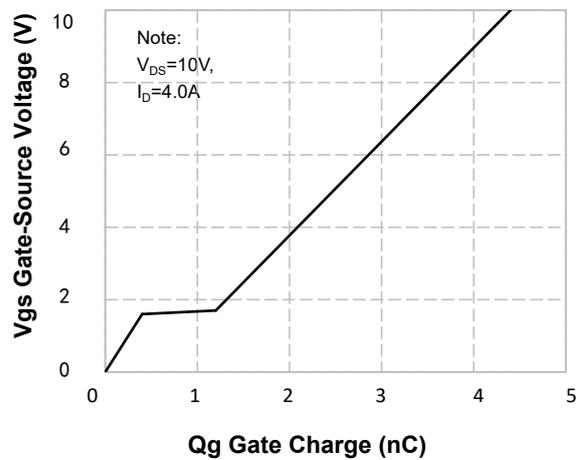


Figure 6. Gate Charge Characteristics

N- Channel Typical Characteristics (Continued)

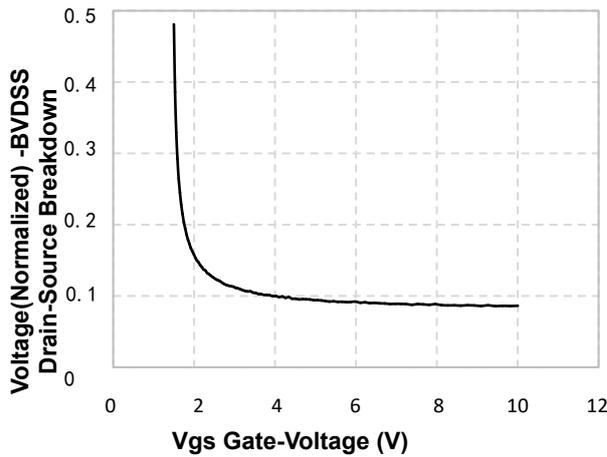


Figure 7. Breakdown Voltage Variation vs Gate-Voltage

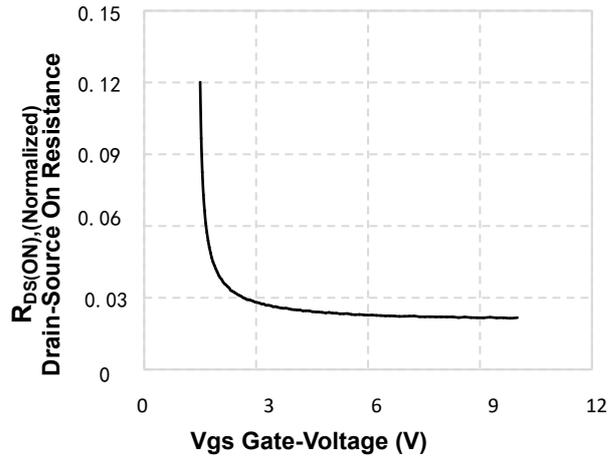


Figure 8. On-Resistance Variation vs Gate Voltage

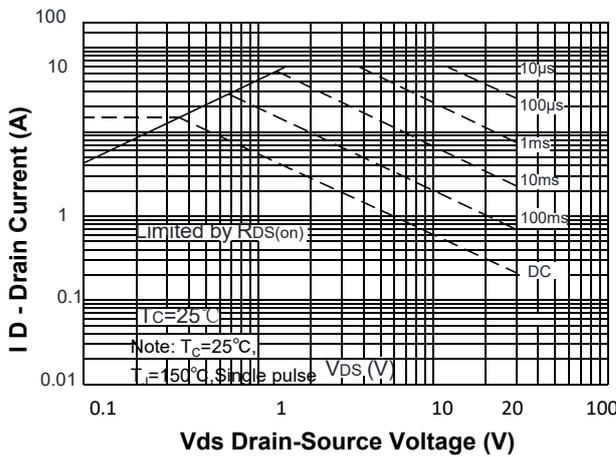


Figure 9. Maximum Safe Operating Area

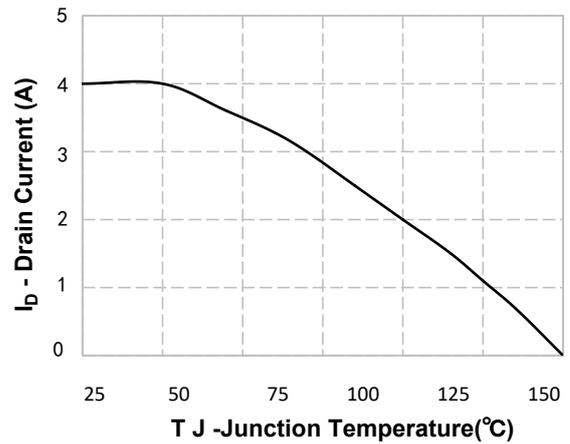


Figure 10. Maximum Continuous Drain Current vs Temperature

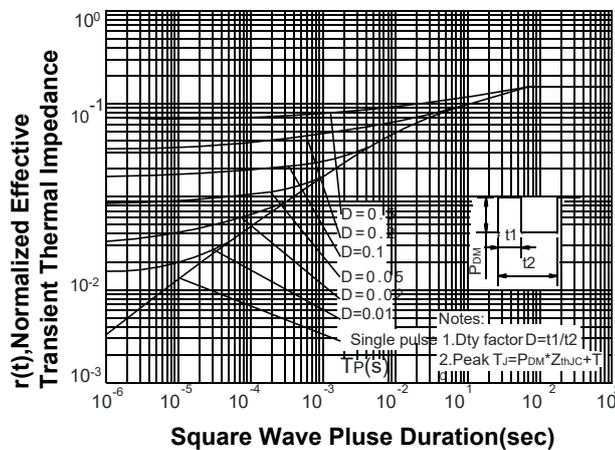
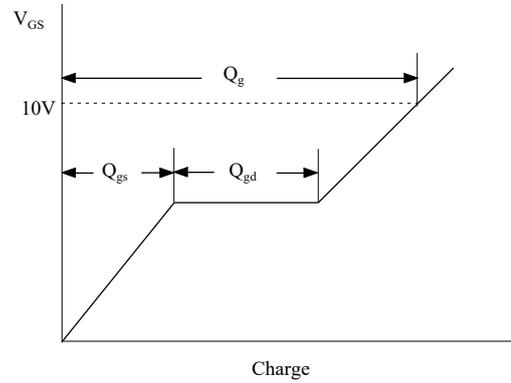
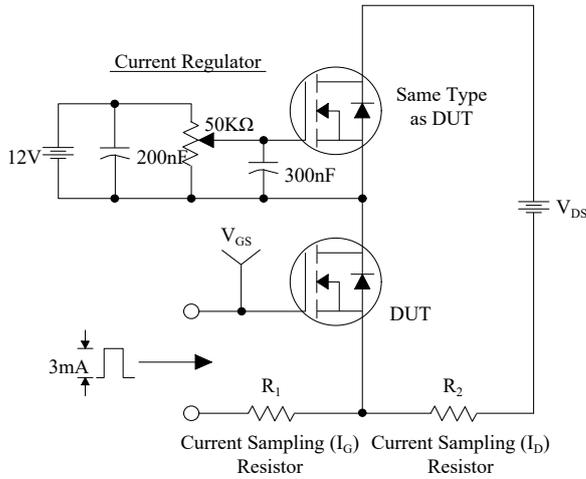
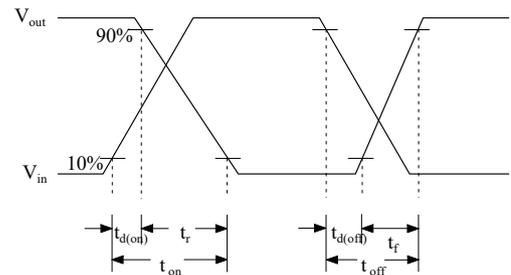
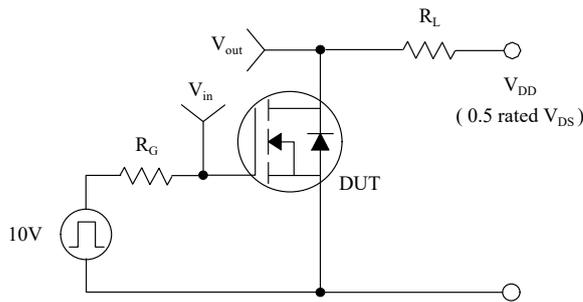


Figure 11. Transient Thermal Response Curve

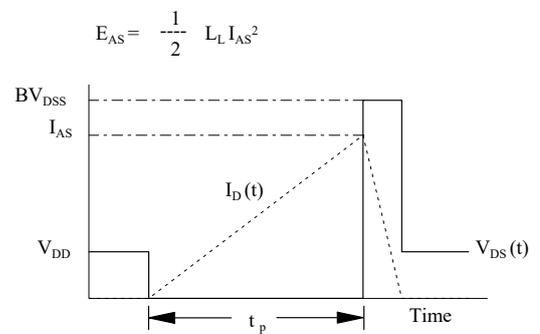
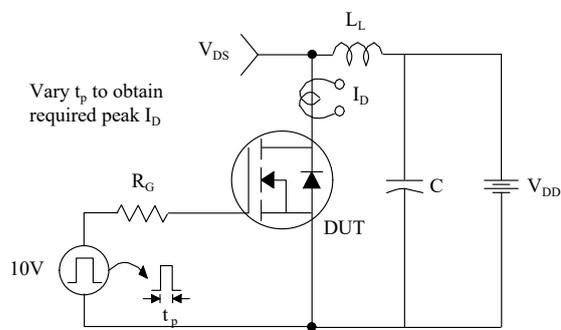
Gate Charge Test Circuit & Waveform



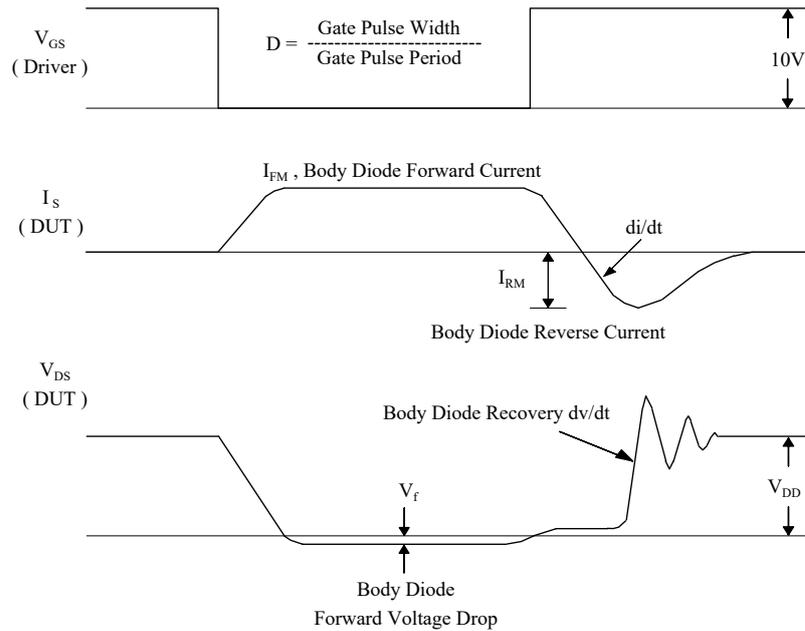
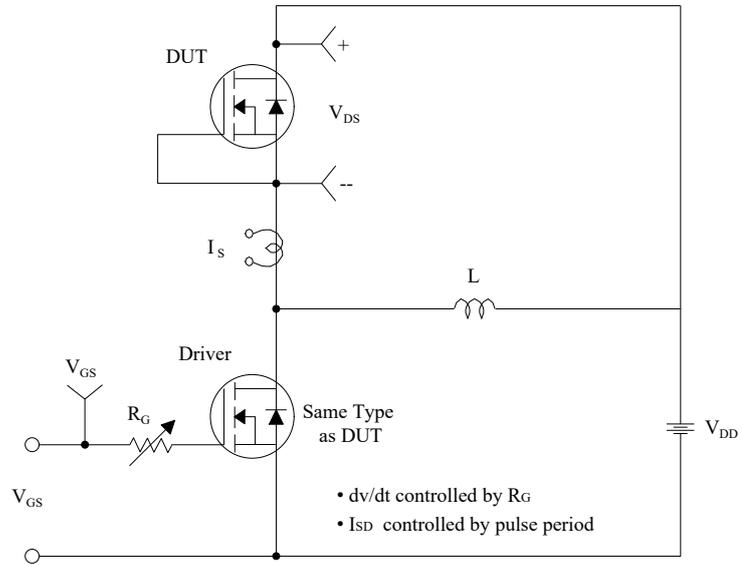
Resistive Switching Test Circuit & Waveforms



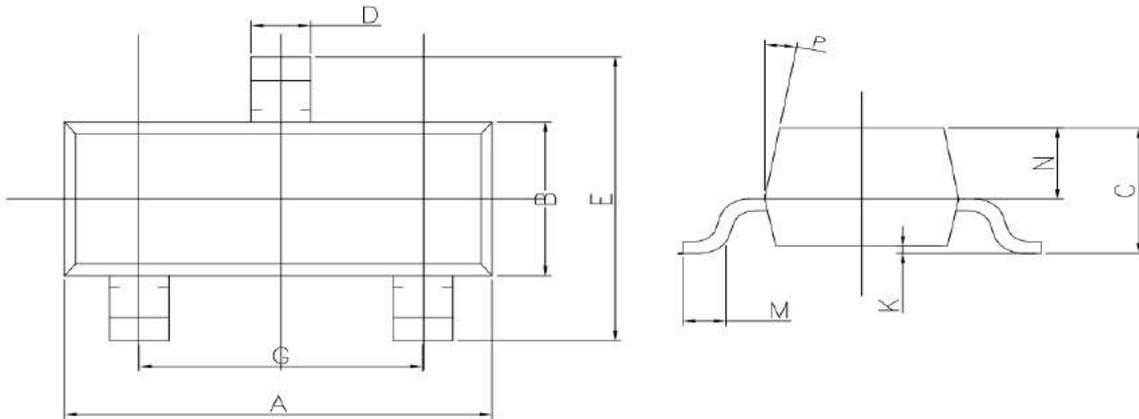
Unclamped Inductive Switching Test Circuit & Waveforms



Peak Diode Recovery dv/dt Test Circuit & Waveforms



SOT-23 Package Information



DIM	MILLIMETERS
A	2.90 ± 0.1
B	1.30 ± 0.10
C	0.90 ~ 1.15
D	0.40 ± 0.1
E	2.40 ± 0.15
G	1.90 ± 0.10
K	0.00~0.10
M	0.30MIN
N	0.60 ± 0.10
P	10°TYP

Customer Service

Sales and Service:

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